Diode Semiconductor Device - Page 1 of 1



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## Inclosure Material:

Glass

# **Overall Length:**

Between 0.140 inches and 0.180 inches

## **Terminal Length:**

1.000 inches

## **Overall Diameter:**

Between 0.060 inches and 0.080 inches

### Mounting Method:

Terminal

#### **Features Provided:**

Hermetically sealed case

#### Semiconductor Material:

Silicon

#### Voltage Rating In Volts Per Characteristic:

-2.0 breakdown voltage, dc

#### **Current Rating Per Characteristic:**

100.00 microamperes forward current, average peak

### **Power Rating Per Characteristic:**

100.0 milliwatts small-signal input power, common-collector preset

## Maximum Operating Tempurature Per Measurement Point:

125.0 degrees celsius junction

# **Test Data Document:**

08771-19a116052 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing,

etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)

#### Terminal Type And Quantity:

2 uninsulated wire lead

#### Shelf Life:

N/a

#### Unit Of Measure:

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#### Demilitarization:

No

#### Fiig:

A110a0